

STN749

MEDIUM CURRENT, HIGH PERFORMANCE, LOW VOLTAGE PNP TRANSISTOR

Ordering Code	Marking	
STN749	N749	

- VERY LOW COLLECTOR TO EMITTER SATURATION VOLTAGE
- DC CURRENT GAIN, h_{FE} > 100
- 3 A CONTINUOUS COLLECTOR CURRENT
- SOT-223 PLASTIC PACKAGE FOR SURFACE MOUNTING CIRCUITS
- AVAILABLE IN TAPE AND REEL PACKING

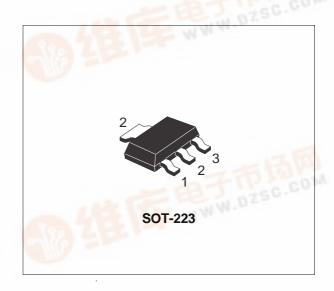
APPLICATIONS

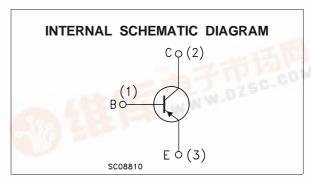
- POWER MANAGEMENT IN PORTABLE EQUIPMENT
- VOLTAGE REGULATION IN BIAS SUPPLY CIRCUITS
- SWITCHING REGULATOR IN BATTERY CHARGER APPLICATIONS
- HEAVY LOAD DRIVER

DESCRIPTION

The device is manufactured in low voltage PNP Planar Technology by using a "Base Island" layout.

The resulting Transistor shows exceptional high gain performance coupled with very low saturation voltage.





ABSOLUTE MAXIMUM RATINGS

Symbol Parameter		Value	Unit
V _{CBO}	Collector-Base Voltage (I _E = 0)	-35	V
V _{CEO} Collector-Emitter Voltage (I _B = 0)		-25	V
V _{EBO}	Emitter-Base Voltage (I _C = 0)	-5	V
Ic	Collector Current	-3	Α
I _{CM} Collector Peak Current (t _p < 5 ms)		-6	Α
P _{tot}	Total Dissipation at T _{amb} = 25 °C	1.6	W
T _{stg}	Storage Temperature	-65 to 150	°C
Tj	Max. Operating Junction Temperature	150	°C



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THERMAL DATA

		R _{thj-amb} •	Thermal Resistance Junction-Ambient	Max	78	°C/W
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Device mounted on a PCB area of 1 cm².

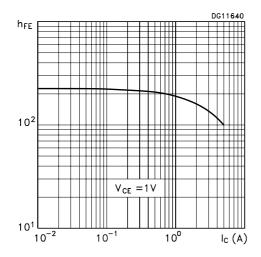
ELECTRICAL CHARACTERISTICS (T_{case} = 25 °C unless otherwise specified)

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
I _{CBO}	Collector Cut-off Current (I _E = 0)	V _{CB} = -30 V V _{CB} = -30 V	T _j = 100 °C			-100 -10	nA μA
I _{EBO}	Emitter Cut-off Current (I _C = 0)	V _{EB} = -4 V				-100	nA
V _{(BR)CEO*}	Collector-Emitter Breakdown Voltage (I _B = 0)	I _C = -10 mA		-25			V
V _{(BR)CBO}	Collector-Base Breakdown Voltage (I _E = 0)	I _C = -100 μA		-35			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage (I _C = 0)	I _E = -100 μA		-5			V
V _{CE(sat)} *	Collector-Emitter Saturation Voltage	I _C = -1A I _C = -3A	$I_B = -100 \text{ mA}$ $I_B = -300 \text{ mA}$			-0.3 -0.6	V V
V _{BE(sat)} *	Base-Emitter Saturation Voltage	I _C = -1 A	I _B = -100 mA			-1.25	V
VBE(on)	Base-Emitter Turn-On Voltage	Ic = -1 A	Vce = -2 V			-1	V
h _{FE} *	DC Current Gain	I _C = -50 mA I _C = -1 A I _C = -2 A I _C = -6 A	V _{CE} = -2 V V _{CE} = -2 V V _{CE} = -2 V V _{CE} = -2V	70 100 75 15		300	

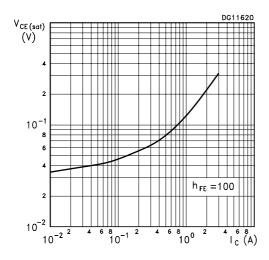
^{*} Pulsed: Pulse duration = 300 μs, duty cycle ≤ 1.5 %

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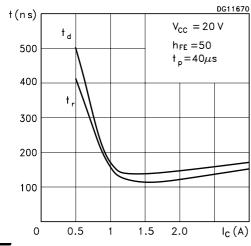
DC Current Gain



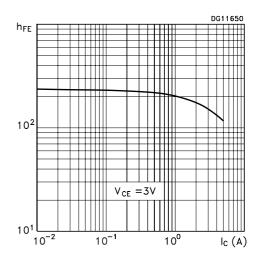
Collector-Emitter Saturation Voltage



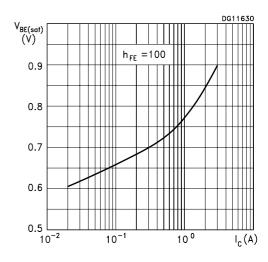
Switching Times Resistive Load



DC Current Gain



Base-Emitter Saturation Voltage



Switching Times Resistive Load

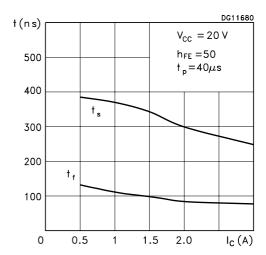
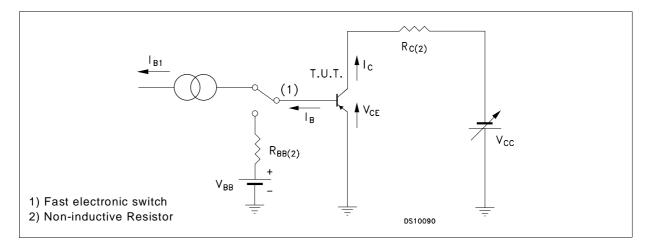
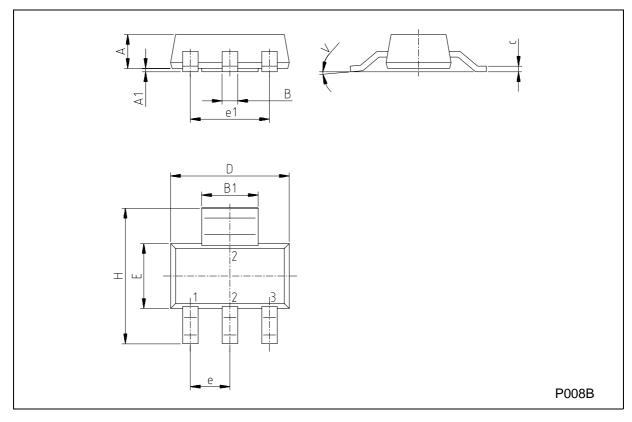


Figure 1: Resistive Load Switching Test Circuit.



SOT-223 MECHANICAL DATA

DIM.	mm			inch		
J.III.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А			1.80			0.071
В	0.60	0.70	0.80	0.024	0.027	0.031
B1	2.90	3.00	3.10	0.114	0.118	0.122
С	0.24	0.26	0.32	0.009	0.010	0.013
D	6.30	6.50	6.70	0.248	0.256	0.264
е		2.30			0.090	
e1		4.60			0.181	
Е	3.30	3.50	3.70	0.130	0.138	0.146
Н	6.70	7.00	7.30	0.264	0.276	0.287
V			10°			10°
A1		0.02				



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